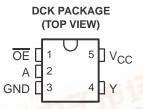
SGES002A - APRIL 2003 - REVISED MAY 2004

- Qualification in Accordance With AEC-Q100†
- **Qualified for Automotive Applications**
- **Customer-Specific Configuration Control** Can Be Supported Along With Major-Change Approval
- **Available in the Texas Instruments** NanoStar™ and NanoFree™ Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max tod of 3.7 ns at 3.3 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- † Contact factory for details. Q100 qualification data available on request.

- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



description/ordering information

This bus buffer gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G125 is a single line driver with a 3-state output. The output is disabled when the output-enable (OE) input is high.

NanoStar™ and NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PACKAGE [‡]		ORDERABLE PART NUMBER	TOP-SIDE MARKING§
-40°C to 125°C	SOT (SC-70) - DCK	Reel of 2875	1P1G125QDCKRQ1	CM_

Package drawings, standard packing quantities, thermal data, symbolization, and PCB design quidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INPU	JTS	OUTPUT
OE	Α	Y
VL.	Н	Н
C O'M	L	L
Н	Χ	Z

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



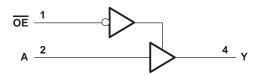


[§] DCK: The actual top-side marking has one additional character that designates the assembly/test site. WWW.DZSC.GOM

SN74LVC1G125-Q1 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 6.5 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 6.5 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 3)	252°C/W
Storage temperature range, T _{stq}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The value of V_{CC} is provided in the recommended operating conditions table.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



SN74LVC1G125-Q1 **SINGLE BUS BUFFER GATE** WITH 3-STATE OUTPUT SGES002A - APRIL 2003 - REVISED MAY 2004

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
.,	0 1 1	Operating	1.65	5.5	.,	
VCC	Supply voltage	Data retention only	1.5		V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
.,		V _{CC} = 2.3 V to 2.7 V	1.7			
V_{IH}	High-level input voltage	level input voltage V _{CC} = 3 V to 3.6 V			V	
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
.,		V _{CC} = 2.3 V to 2.7 V	0.00			
V_{IL}	Low-level input voltage	V _{CC} = 3 V to 3.6 V		0.8	V	
		V _{CC} = 4.5 V to 5.5 V		0.3 × V _{CC}		
٧ı	Input voltage	·	0	5.5	V	
VO	Output voltage		0	VCC	V	
		V _{CC} = 1.65 V		-4		
		V _{CC} = 2.3 V	-8			
loh	High-level output current			-16	mA	
		VCC = 3 V		-24		
		V _{CC} = 4.5 V		-24		
		V _{CC} = 1.65 V		4		
		V _{CC} = 2.3 V		8		
loL	Low-level output current			16	mA	
		VCC = 3 V		24		
		V _{CC} = 4.5 V	24		1	
		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}, 2.5 \text{ V} \pm 0.2 \text{ V}$	20			
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		V _{CC} = 5 V ± 0.5 V				
TA	Operating free-air temperature	·	-40	125	°C	

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SN74LVC1G125-Q1 SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

F	ARAMETER	TEST CONDITIONS	vcc	MIN	TYP	MAX	UNIT	
		I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} -0.1				
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2				
		$I_{OH} = -8 \text{ mA}$	2.3 V	1.9				
VOH		$I_{OH} = -16 \text{ mA}$	- 1/	2.4			V	
		$I_{OH} = -24 \text{ mA}$	3 V	2.3				
		I _{OH} = -24 mA	4.5 V	3.8				
		I _{OL} = 100 μA	1.65 V to 5.5 V			0.1		
		I _{OL} = 4 mA	1.65 V			0.45		
		I _{OL} = 8 mA	2.3 V			0.3		
VOL		I _{OL} = 16 mA	2.1/		0.4		V	
		I _{OL} = 24 mA	3 V			0.55		
		I _{OL} = 24 mA	4.5 V			0.55		
II	A or OE inputs	V _I = 5.5 V or GND	0 to 5.5 V			±5	μΑ	
loff		V _I or V _O = 5.5 V	0			±10	μΑ	
loz		V _O = 0 to 5.5 V	3.6 V			10	μΑ	
ICC		$V_I = 5.5 \text{ V or GND}, \qquad I_O = 0$	1.65 V to 5.5 V			10	μΑ	
ΔlCC		One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 5.5 V			500	μΑ	
Ci		V _I = V _{CC} or GND	3.3 V		4		pF	

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	V _{CC} = ± 0.		V _{CC} ± 0.		UNIT
	(INPUT) (OUTPUT	(001P01)	MIN	MAX	MIN	MAX	
^t pd	Α	Υ	1	5.1	1	4.1	ns
t _{en}	ŌĒ	Υ	1	6	1	5	ns
t _{dis}	ŌĒ	Υ	1	5	0.5	4.2	ns

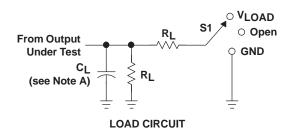
operating characteristics, T_A = 25°C

PARAMETER			TEST CONDITIONS	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
		Outputs enabled		19	21	_
C _{pd} Power dissipation capacitance		Outputs disabled	f = 10 MHz	2	4	pF



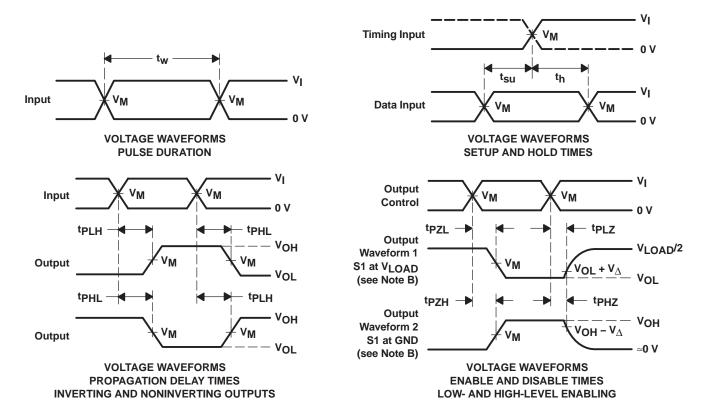
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PARAMETER MEASUREMENT INFORMATION



TEST	S1
tpLH/tpHL	Open
tPLZ/tPZL	VLOAD
tPHZ/tPZH	GND

.,	INPUTS		.,	.,		_	.,
VCC	VI	t _r /t _f	VM	VLOAD	CL	RL	$v_{\scriptscriptstyle\Delta}$
3.3 V ± 0.3 V 5 V ± 0.5 V	3 V VCC	≤2.5 ns ≤2.5 ns	1.5 V V _{CC} /2	6 V 2×V _{CC}	50 pF 50 pF	500 Ω 500 Ω	0.3 V 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{Ω} = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

25-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing		ckage Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
1P1G125QDCKRQ1	ACTIVE	SC70	DCK	5 3	000	None	Call TI	Level-1-235C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

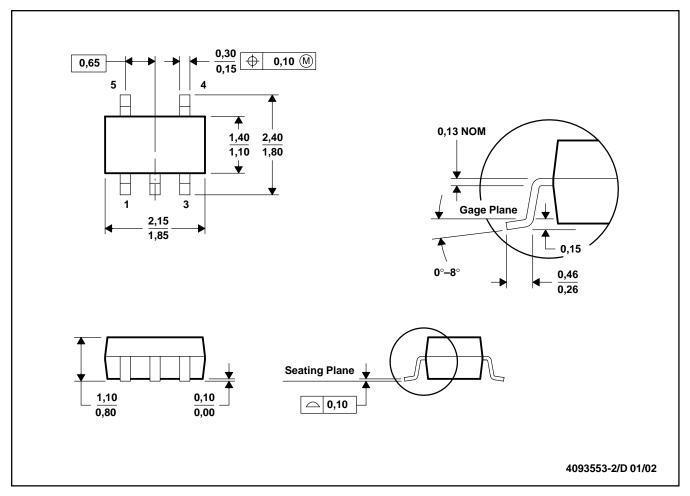
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203

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